

Tuning the superfluid - Mott insulator transition in a resonantly strongly driven Bose - Einstein condensate in an optical lattice.

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Abstract

We have studied the superfluid - Mott insulator transition in a BEC confined in an optical lattice and driven by an additional external electromagnetic field, which excites another internal state. It is shown that due to resonant strong driving the critical values of the transition parameter depend on external field parameters (the Rabi frequency and the detuning from resonance) and can be tuned to a given value. It is also shown that for driven system there are two optical potential depths at a phase transition, which are always more than without driving.

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The experimental observation of Bose-Einstein condensation in a dilute gas of ultracold trapped atoms [1-3] has generated much interest in manipulating such coherent matter by external electromagnetic fields. Recently, atoms have been confined in optical potentials created by standing light waves [4, 5], with the wavelength of the optical potential much smaller than the dimensions of the trap. Considerable work has been done, in the last decade, to determine the ground state phase diagram of correlated bosons on such a lattice. The bosons can undergo a transition from superfluid to insulator. Strong competition between potential and kinetic energies begets a quantum phase transition. The on - site repulsion can produce a Mott insulating phase with a quantum phase transition to a superfluid as the interaction strength weakens. A seminal experiment by Greiner and collaborators [5] demonstrated a quantum phase transition in a Bose - Einstein condensate (BEC) from a superfluid (SF) state into a Mott insulator (MI) state, by varying the lattice laser intensity, as proposed theoretically in [6]. The quantum phase transitions have attracted much interest in recent years. These transitions are accomplished by changing not the temperature, but some parameter in the Hamiltonian of the system; for a BEC in an optical lattice this parameter is the lattice laser intensity, for solid state systems, for example, the magnetic field in a quantum - Hall system, or the charging energy in Josephson - junction arrays.

In this paper, we propose a manipulation of the quantum phase transition of a BEC in an optical lattice by an additional external electromagnetic field. This basic idea of my paper is using the external field to drive transitions between internal states for atoms in an optical lattice. This driving alter the balance between self - interactions of the atoms in lattice site and hopping of the atoms between the sites, and thereby modify the superfluid - Mott insulator phase transition.

An applied resonant field excites another internal state of the BEC, which is why the populations of two coupled states are varied. Without driving a quantum phase transition in an one - component BEC is a single - channel problem, but with resonant driving it becomes a two - channel problem, in which every channel has competition between kinetic

and potential energies. The populations of the coupled states are varied. As a result, the effective on - site interaction and the effective tunneling in these two channels, which depend on the population, are also changed. However, due to this varying population the variations of the on - site interaction and the tunneling are different; therefore, the balance between kinetic and potential energies, which determines a phase transition, is altered. As a result, we have a modification of the quantum phase transition by the applied resonant field, which is determined by the two channels. It is shown that for each channel, the critical value of the ratio of the interaction strength and the tunneling depends on the population, which for the strong driving is the Rabi oscillations. Therefore, in the regime of the time - dependent Rabi oscillations the MI - SF and the reverse SF - MI transitions occur during a period of the Rabi frequency. The frequency of this oscillating superfluidity is determined by the driving strength. In the steady state driving regime the critical value of the ratio of the parameters is always increased, and two optical potential depths at the phase transition for the driven system are always higher than without driving. Therefore, this effect opens the possibility creating a superfluid state from a initially Mott insulator state. The critical values of the driven system depend on the parameters of the external field (the Rabi frequency and the detuning from resonance); in particular, the quantum phase transition can be induced by varying only the detuning with the fixed field amplitude. We can tune the critical values of the quantum phase transition to a given value. Our proposal of manipulating a quantum phase transition can be applied to solid state systems. For example, in a quantum - Hall system the resonant driving may be a novel way of modification a quantum phase transition besides using the magnetic field which controls the transition between different quantized Hall phases.

We consider a two - component Bose - Einstein condensate in an optical lattice in the presence of an additional external electromagnetic field which couples the two components (the different internal states). The energy eigenstates are Bloch states, and an appropriate superposition of Bloch states yields a set of Wannier functions which are localized on the individual lattice sites. An external field couples the two states a and b , and an atom is always

in the superposition of these states. The system is driven by a two - photon Raman pulse, the strength of which we characterize by the Rabi frequency Ω_R . We will consider as the two distinct internal states a and b coupled by the external time - dependent field two different vibrational states in the Wannier basis, where the initial state a is the lowest vibrational state of the harmonic oscillator with $n = 0$ and the state b is the excited vibrational state with $n \neq 0$. Depending on the relative strength of the atom - atom interaction, the system may lie in the Rabi regime or in the Josephson regime. The equations of motion of a strongly (the Rabi regime) driven [7, 8] two - component BEC resemble the Bloch equations describing a driven two - level system if the external driving field $\hbar\Omega_R$ is much larger than the difference in the two - body interaction (the " charging" [9] energy E_C which is proportional to $U_a + U_b - 2U_{ab}$). For the two - body interaction, we use a contact potential, $V_l(\mathbf{x} - \mathbf{x}') = U_l\delta(\mathbf{x} - \mathbf{x}')$, here $\{l = a, b\}$; the coupling constants, U_l , are expressed in terms of the s - wave scattering lengths by $U_l = \frac{4\pi\hbar^2 a_l}{m}$, where a_a and a_b are the scattering lengths for collisions between two atoms in states a and b , respectively, while a_{ab} is the scattering length for collisions between atoms in different internal states. The driving field is a spatially uniform field of the two - photon pulse of Raman type with the wavelengths much larger than the dimensions of a BEC. The external resonant field excites the higher internal state, while, the energies involved in the one channel dynamics to be small compared to the excitation energies to the higher internal state. In this case of the strong driving we can solve the problem in two steps. The first is taking account only of the strong external field Ω_R ; in the result of this step we have the Bloch equations solution φ_l where the functions φ_l are determined by the parameters of the external field (the Rabi frequency Ω_R and the detuning δ from resonance). This Rabi solution of the Bloch equations obey the condition $|\varphi_a|^2 + |\varphi_b|^2 = 1$. And, the wave function of a two - level system is

$$\Psi = \varphi_a\Psi_a + \varphi_b\Psi_b. \quad (1)$$

In this two - state Hilbert space the system is described by the effective Hamiltonian H_{eff} . And, a second step is taking account of the remaining terms of the Hamiltonian. As a result,

using Eq.(1) we can write the effective Hamiltonian in the second - quantization notations for the boson field operators

$$\begin{aligned}
H_{eff} = & \int d^3x [\Psi_a^\dagger(\mathbf{x}, t) \left(-\frac{\hbar^2 \nabla^2}{2m} + V_0(\mathbf{x}) + \frac{\hbar\delta}{2} \right) \Psi_a(\mathbf{x}, t) \varphi_a^2 + \Psi_b^\dagger(\mathbf{x}, t) \left(-\frac{\hbar^2 \nabla^2}{2m} + V_0(\mathbf{x}) - \frac{\hbar\delta}{2} \right) \Psi_b(\mathbf{x}, t) \varphi_b^2 + \\
& \int d^3x d^3x' [\Psi_a^\dagger(\mathbf{x}, t) \Psi_a^\dagger(\mathbf{x}', t) V_a(\mathbf{x} - \mathbf{x}') \Psi_a(\mathbf{x}', t) \Psi_a(\mathbf{x}, t) \varphi_a^4 + \\
& \Psi_b^\dagger(\mathbf{x}, t) \Psi_b^\dagger(\mathbf{x}', t) V_b(\mathbf{x} - \mathbf{x}') \Psi_b(\mathbf{x}', t) \Psi_b(\mathbf{x}, t) \varphi_b^4 + 2 \Psi_a^\dagger(\mathbf{x}, t) \Psi_b^\dagger(\mathbf{x}', t) V_{ab}(\mathbf{x} - \mathbf{x}') \Psi_b(\mathbf{x}', t) \Psi_a(\mathbf{x}, t) \varphi_a^2 \varphi_b^2],
\end{aligned} \tag{2}$$

where $V_0(\mathbf{x})$ is the optical lattice potential, usually, the optical lattice potential has the form $V_0(\mathbf{x}) = \sum_{j=1}^3 V_{jo} \sin^2 kx_j$ with wave vectors $k = \frac{2\pi}{\lambda}$ and λ the wavelength of the laser beams. The atomic field operators have been written in the rotating wave approximation and, consequently, in Eq.(2) there appears a detuning, $\delta = \omega_0 - \omega_d$, where $\hbar\omega_0$ is the energy difference between the two internal states, and $\omega_d = \omega_L - \omega_S$ is the frequency of the Raman drive. Following Ref. [6] the boson field operators can be represent by an expansion in the Wannier basis, which is a sum over the lattice i , $\Psi_a(\mathbf{x}) = \sum_i a_i w_0(\mathbf{x} - \mathbf{x}_i)$, $\Psi_b(\mathbf{x}) = \sum_i b_i w_n(\mathbf{x} - \mathbf{x}_i)$, where the operators a_i and b_i are the operators on lattice site i ; the annihilation and creation operators a_i and $a_i^\dagger$ (b_i and $b_i^\dagger$) obey the canonical commutation relations $[a_i, a_j^\dagger] = \delta_{ij}$ ($[b_i, b_j^\dagger] = \delta_{ij}$).

As a result, in the tight - binding approximation a two - band Bose - Hubbard Hamiltonian of a strongly resonant driven BEC is

$$\begin{aligned}
H_{BH} = & -t_{aa} \sum_{\langle i,j \rangle} a_i^\dagger a_j \varphi_a^2 - t_{bb} \sum_{\langle i,j \rangle} b_i^\dagger b_j \varphi_b^2 \\
& + \frac{U_{aa}}{2} \sum_i a_i^\dagger a_i (a_i^\dagger a_i - 1) \varphi_a^4 + \frac{U_{bb}}{2} \sum_i b_i^\dagger b_i (b_i^\dagger b_i - 1) \varphi_b^4 + U_{ab} \sum_i a_i^\dagger a_i b_i^\dagger b_i \varphi_a^2 \varphi_b^2 + \\
& - \mu \left(\sum_i a_i^\dagger a_i \varphi_a^2 + \sum_i b_i^\dagger b_i \varphi_b^2 \right) + \delta \sum_i b_i^\dagger b_i \varphi_b^2,
\end{aligned} \tag{3}$$

where the sum in the two terms runs over all nearest neighbors denoted by $\langle i, j \rangle$. The term involving the chemical potential μ is added as the calculation is in the grand - canonical ensemble at temperature $T = 0$. The first and second sum measure the boson kinetic energy [10], and the parameter t_{ll} is the hopping matrix element for channel l between

neighboring lattice sites i, j ; the parameters U_{aa}, U_{bb}, U_{ab} characterize the strength of the on-site interaction of two atoms on the lattice site i . These parameters are defined as

$$\begin{aligned} t_{aa} &= \int d^3x w_0^*(\mathbf{x} - \mathbf{x}_i) \left[-\frac{\hbar^2}{2m} \nabla^2 + V_0(\mathbf{x}) \right] w_0(\mathbf{x} - \mathbf{x}_j), \\ t_{bb} &= \int d^3x w_n^*(\mathbf{x} - \mathbf{x}_j) \left[-\frac{\hbar^2}{2m} \nabla^2 + V_0(\mathbf{x}) \right] w_n(\mathbf{x} - \mathbf{x}_i), \\ U_{aa} &= U_a^s \int d^3x |w_0(\mathbf{x})|^4, U_{bb} = U_b^s \int d^3x |w_n(\mathbf{x})|^4, U_{ab} = U_{ab}^s \int d^3x |w_0(\mathbf{x})|^2 |w_n(\mathbf{x})|^2. \end{aligned} \quad (4)$$

The parameters t_{00} and U_{00} of the one-band Bose-Hubbard model depend on the potential depth V_o , and they were calculated analytically in Ref.[11] in the tight-binding limit in terms of the microscopic parameters of the atoms in the optical lattice using the approximation [11] the Wannier states by the harmonic oscillator wave function $w_n(\mathbf{x} - \mathbf{x}_i)$ of number n .

In order to describe the zero-temperature quantum phase transition from the superfluid to the Mott insulator phase analytically, it is necessary to make some appropriate mean-field approximation in using the Hamiltonian (Eq.(3)). A mean-field theory, developed in [11], constructs a consistent mean-field theory by substituting $a_i^\dagger a_j = \langle a_i^\dagger \rangle a_j + a_i^\dagger \langle a_j \rangle - \langle a_i^\dagger \rangle \langle a_j \rangle$, where $\langle a_i^\dagger \rangle = \langle a_i \rangle$ is the expectation value on site i . Following this theory [11], which exploited the usual Landau procedure for a second-order phase transition, we obtain the critical value of the ratio of the on-site interaction and hopping parameters

$$\left(\frac{U_{ll}}{t_{ll}} \right)^{(cr)} \varphi_l^2 = 2d(2g + 1 + \sqrt{(2g + 1)^2 - 1}), \quad (5)$$

where the number of nearest neighbors $2d$, d is the number of dimensions, g is the integer number of particles at each site i . In these two equations the functions φ_l coupled by the normalization condition. For a single channel (one-component model) $\varphi_0 \equiv 1$ and these equations are reduced to the well-known result for the critical value [11]. Note that the chemical potential μ_c at the critical point is calculated also by the cross-interaction U_{ab} between the channels.

Let us first consider the time-dependent regime of the Rabi oscillations for zero detuning, $\delta = 0$, in this case we have the time-dependent functions $\varphi_l(t)$. In this regime the Eqs.(5)

are valid if the Rabi oscillations period is larger than the nonequilibrium dynamical times (the characteristic time scales are the time of establishing of the SF state, the restoration time of the phase coherence or the dephasing time). The nonequilibrium dynamic time for trapped bosonic atoms in an optical lattice potential was considered in Ref. [12] and was shown that the characteristic time of the dynamical restoration of the phase coherence in the domain of a quantum phase transition is the integer of the order of 10 multiplied by a Josephson time $\hbar/t$. The initial phase of the BEC is MI phase for $V_0 \succ V_0^{cr}$, where V_0^{cr} is the optical potential depth at the SF - MI transition without driving. The functions $\varphi_l(t)$ determine the population ρ_l of the states l , which oscillate as $\cos^2 \Omega_R t$ for channel a and $\sin^2 \Omega_R t$ for channel b . Accordingly, during the period $2\pi/\Omega_R$ of the Rabi oscillations the transition from MI to SF phases and the reverse transition occur. Really, for the channel a at the point Θ_1 there is the MI - SF transition, at $(\pi - \Theta_1)$ - the opposite SF - MI transition. For times of the Rabi oscillations period from $t = 0$ until $t_1 = \Theta_1/\Omega_R$ and from $(\pi - \Theta_1)$ until π the channel a is in the MI phase, from Θ_1 until $(\pi - \Theta_1)$ there is the SF phase. Correspondingly, for the channel b with the opposite time - dependence of population at Θ_2 there are the SF - MI transition, at $(\pi - \Theta_2)$ the MI - SF transition. In the channel b , until $t_2 = \Theta_2/\Omega_R$ and from $(\pi - \Theta_2)$ until π is in the SF phase, from Θ_2 until $(\pi - \Theta_2)$, there is the MI phase. Thus, both channels have the superfluid - Mott insulator transition twice in each half - Rabi period. The frequency of this oscillating superfluidity is determined by the driving strength. The time - averaged population N_{dr} of SF phase of a driven BEC, which without driving is in the MI phase, is

$$\frac{N_{dr}(V_0)}{N_0} = \frac{\pi + 2[\Theta_2(V_0) - \Theta_1(V_0)] - [\sin 2\Theta_1(V_0) + \sin 2\Theta_2(V_0)]}{2\pi}, \quad (6)$$

where N_0 is the concentration of a nondriven BEC in the SF phase for $V_0 \prec V_0^{cr}$. Here

$$\Theta_1(V_0) = \arccos \sqrt{\frac{\Delta U_{00}(V_0)}{\Delta t_{00}(V_0)}}, \Theta_2(V_0) = \arcsin \sqrt{\frac{\Delta U_{00}(V_0)}{\Delta t_{00}(V_0)} \frac{\Delta U_{00}^{nn}}{\Delta t_{00}^{nn}}}, \quad (7)$$

where $\Delta U_{00}(V_0) \equiv \frac{U_{00}(V_0^{cr})}{U_{00}(V_0)}$, $\Delta t_{00}(V_0) \equiv \frac{t_{00}(V_0^{cr})}{t_{00}(V_0)}$; the ratios, which are calculated in Eqs.(10) below for $n = 1$, are $\Delta U_{00}^{nn} \equiv \frac{U_{nn}}{U_{00}}$, $\Delta t_{00}^{nn} \equiv \frac{t_{nn}}{t_{00}}$. If $\frac{\Delta U_{00}(V_0)}{\Delta t_{00}(V_0)} \frac{\Delta U_{00}^{nn}}{\Delta t_{00}^{nn}} \geq 1$ then $\Theta_2(V_0) = \pi/2$.

In the steady state driving regime every atom is in the stationary superposition of two states, which populations are determined by the Rabi frequency and the detuning from resonance. We have two critical values of the transition parameters of the driven system $(U_u/t_u)_{dr}^{(cr)}$, $\{l = a, b\}$. The dependence $U_u(V_0), t_u(V_0)$ for every channel determines two optical potential depths $V_{0(dr)}^{(a)cr}$ and $V_{0(dr)}^{(b)cr}$ at a phase transition, correspondingly. The critical value of parameter of a phase transition for the driven system $(U_u/t_u)_{dr}^{(cr)}$ is always higher than without driving $(U_u/t_u)_0^{(cr)}$. For the channel a

$$\frac{(U_{00}/t_{00})_0^{(cr)}}{(U_{00}/t_{00})_{dr}^{(cr)}} = 1 - \frac{1}{2} \left[1 + \left(\frac{\delta}{\Omega_R} \right)^2 \right]^{-1}. \quad (8)$$

Therefore, there are an interval of the MI phase, in which the driving switches the MI phase to the SF phase. In this band from $(U_{00}/t_{00})_0^{(cr)}$ to $2(U_{00}/t_{00})_0^{(cr)}$, by varying the parameter δ/Ω_R of the external driving, we can tune the critical value to a given value. With increasing the depth of the optical potential, the on - site interaction increases and the tunneling matrix element is reduced. Accordingly, with increasing the critical value of the transition parameter, the optical potential depth $V_{0(dr)}^{(0)cr}$ at a phase transition always increases.

For the channel b the critical value is always more than for the channel a

$$\frac{(U_{nn}/t_{nn})_{dr}^{(cr)}}{(U_{00}/t_{00})_{dr}^{(cr)}} = 2 \left[1 + \left(\frac{\delta}{\Omega_R} \right)^2 \right] - 1. \quad (9)$$

We obtain for $n = 1$ and in the tight - binding limit, $\lambda \gg \beta$, the ratio

$$\frac{U_{11}}{U_{00}} \simeq \frac{3}{8} H_6(0), \quad \frac{t_{11}}{t_{00}} \simeq \left(\frac{\lambda}{2\beta} \right)^2. \quad (10)$$

Here $\beta = \sqrt{\frac{\hbar}{2m\nu_j}}$ is the size of the ground - state oscillator wave function determined by the atomic mass m and the oscillation frequency in the wells (see, for example [6]) $\nu_j = \sqrt{4E_R V_{jo}}/\hbar$, E_R is the recoil energy, $H_6(x)$ is Hermite polynomial. In general, the ratio U_{nn}/U_{00} contains sum over the Hermite polynomials $H_n(0)$ till $4n+2$, and $t_{nn}/t_{00} \simeq (\lambda/2\beta)^{2n}$, For all n there are the inequalities $t_{nn} \gg t_{00}$ and $U_{nn} \gg U_{00}$, this increase t_{nn} and U_{nn} is due to oscillations of the wave function for $n \neq 0$. For example, $t_{11}/t_{00} \sim 64$ and $U_{11}/U_{00} \sim 45$ for sodium [13] where $E_R/\hbar \sim 2\pi \times 10^4 Hz$ for a red detuned laser with $\lambda \simeq 10^3 nm$ and

$V_0 \simeq 16E_R$. Although, the on - site interaction on the higher channel U_{nn} increases with the number n , the tunneling matrix element t_{nn} increases faster, and we can say that the higher channel n is " more superfluid". The ratio U_{nn}/t_{nn} increases also with increasing the optical potential depth V_0 , and because there are the inequalities $U_{nn}/t_{nn} \prec U_{00}/t_{00}$ for the given V_0 , then Eq.(9) yields a relationship $V_{0(dr)}^{(b)cr} \succ V_{0(dr)}^{(0)cr}$.

In summary, the resonant strong driving by a spatially uniform field modify the SF - MI transition in a BEC in an optical lattice by the mechanism of the turning on of the second channel. Therefore, there are the modifications of the main channel and the second channel. As a result, the transition on each channel is controlled by the external field. In the time - dependent driving regime the initial MI phase switches over to the SF phase and the SF phase to the MI phase during the Rabi oscillations period. The frequency of the oscillating superfluidity is determined by the driving strength. In the steady state driving regime, the critical values of the ratio of the on - site interaction and the atomic tunneling rate depend on the external field parameters (the strength and the detuning from resonance). Two critical values of the driven system and, accordingly, two optical potential depths at the phase transition are always more than without driving. The proposed mechanism of manipulating and controlling Bose - Einstein condensates makes it possible to tune the critical value of parameters of the quantum phase transition to a given value.

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